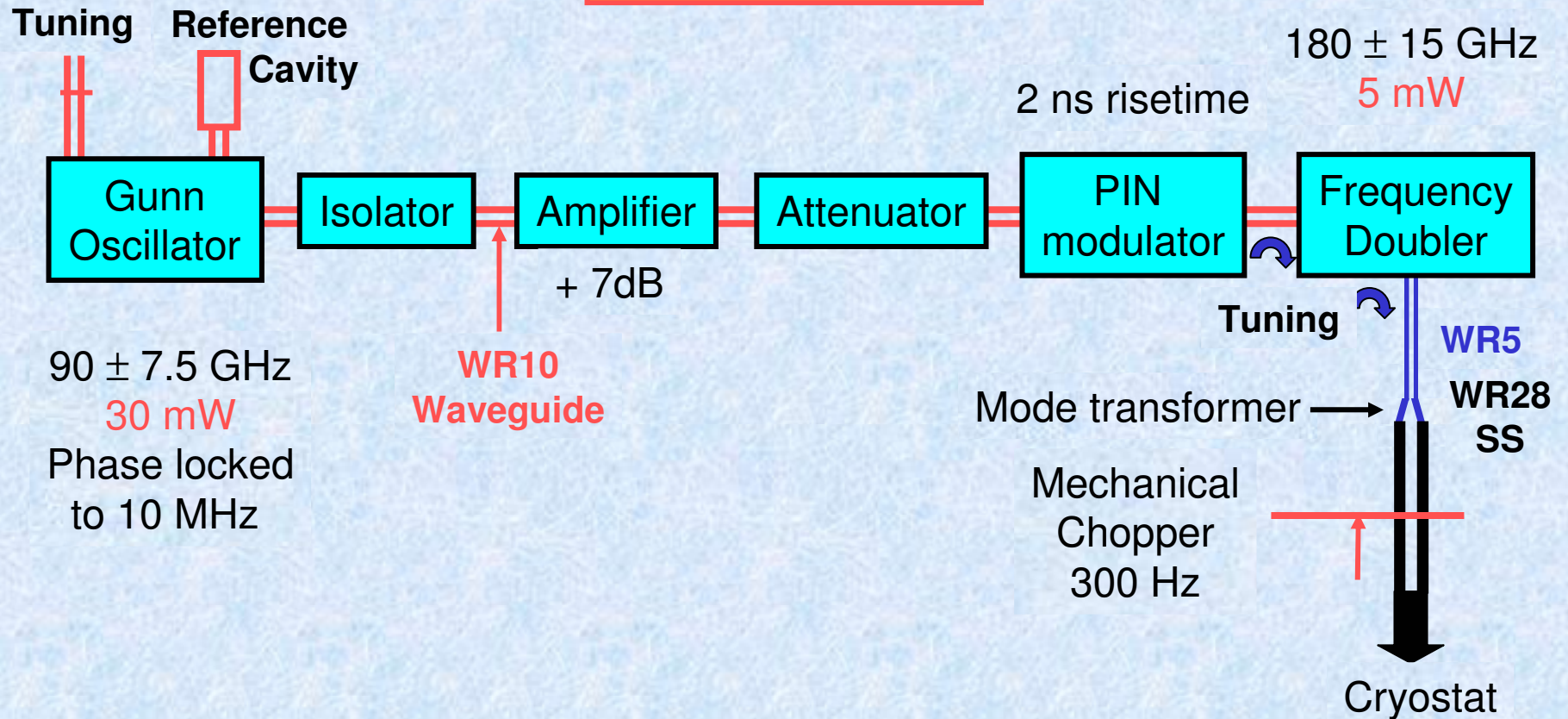


Microwaves for Qubits on Helium

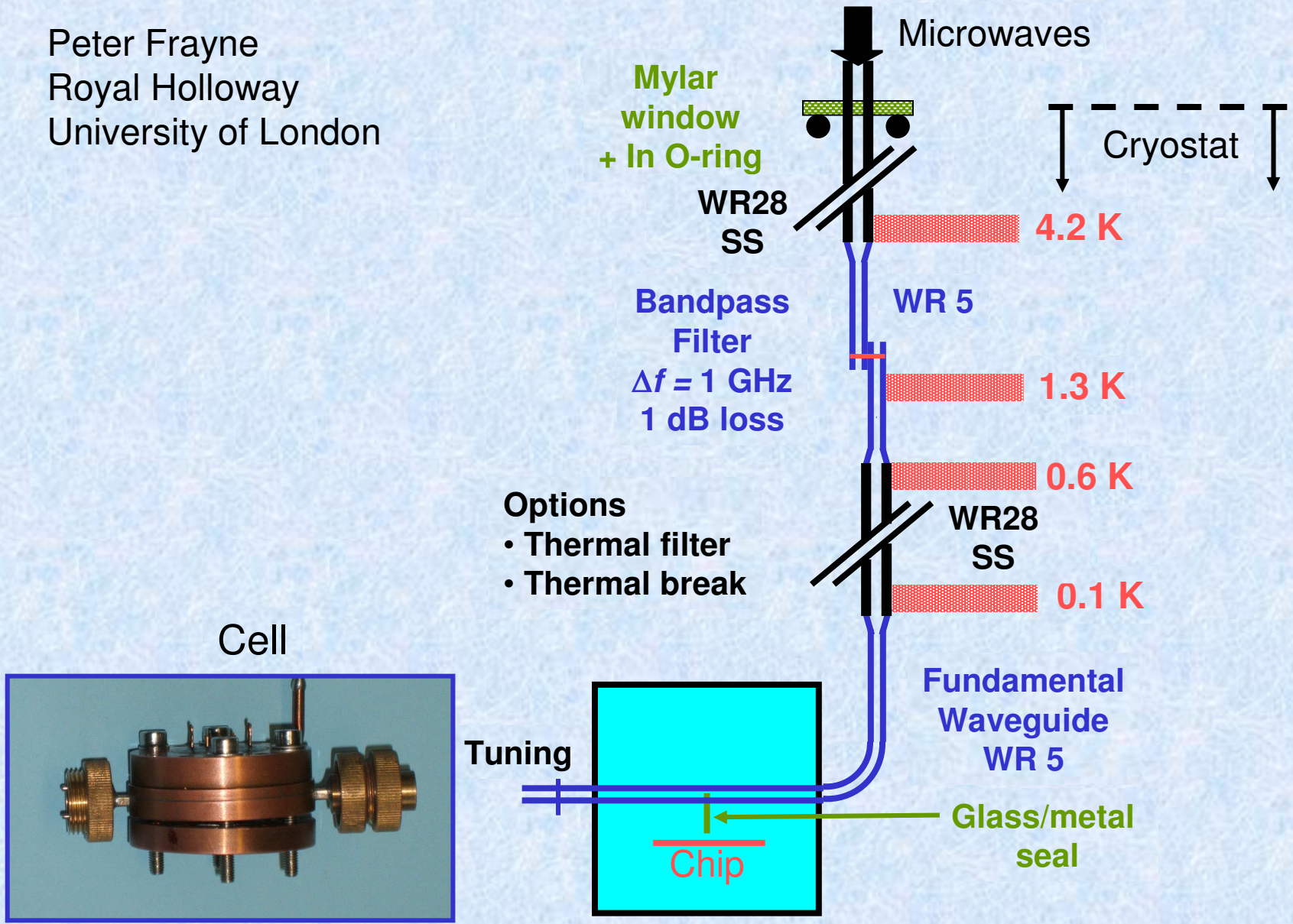
Microwave System 1

Peter Frayne
Royal Holloway
University of London

Rydberg resonance
190 GHz
 $E_z = 10.7 \text{ kV/m}$



Peter Frayne
Royal Holloway
University of London





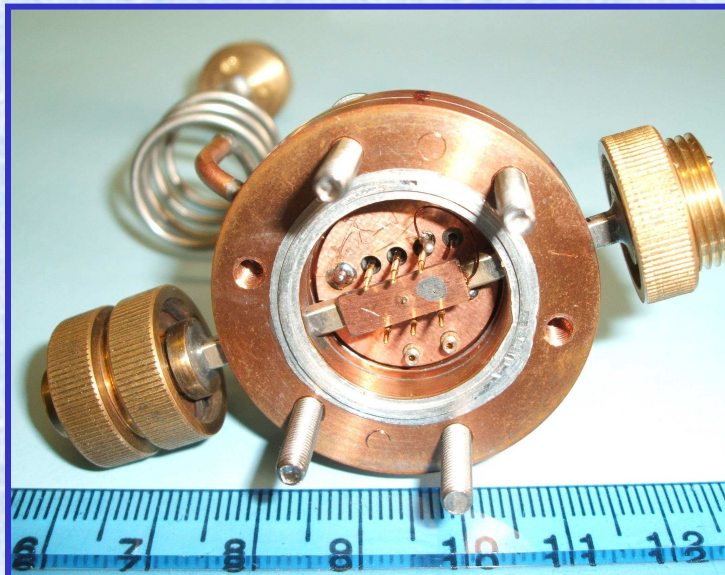
Thermal break in fundamental mode waveguide - two back-to-back waveguide tapers (WR-05 to WR-28) with needle point mountings



Band-pass filter (WR-05) for removing thermal radiation complete with coupling horns to overmoded waveguide (WR-28)



Fundamental mode 'Swan-Neck' coupling piece for microwave cell



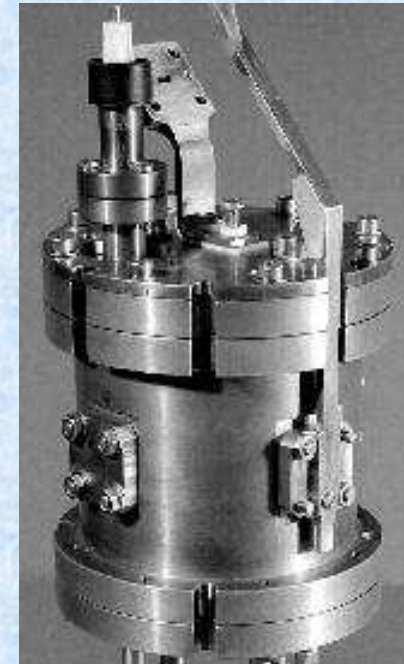
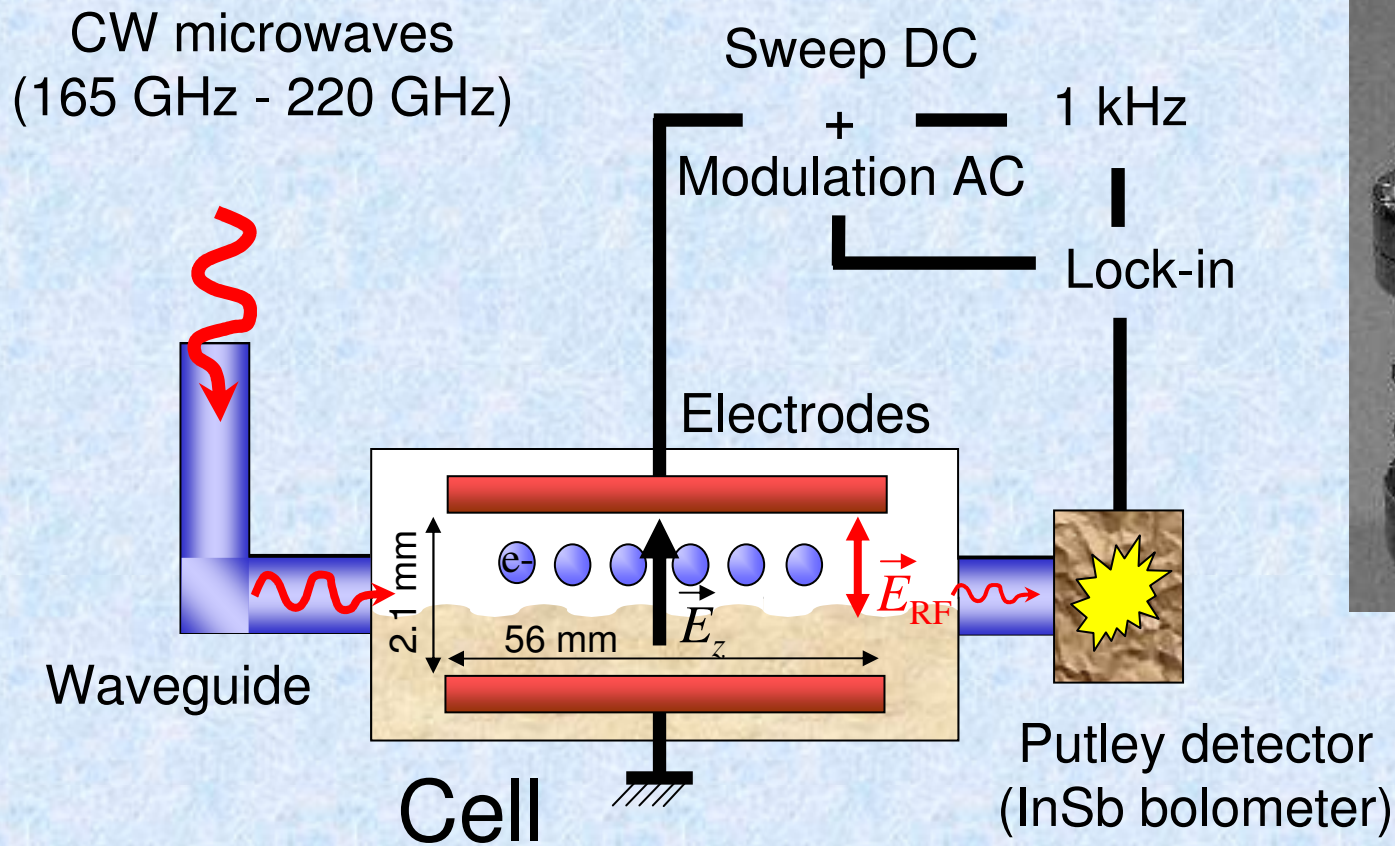
Upper microwave cell showing waveguide and coupling pin

Low Microwave Power

- Stark tuning resonance $f_{12}(E_z)$
- Linewidth $\gamma(T)$
- Temperature dependent resonance $f_{12}(T)$

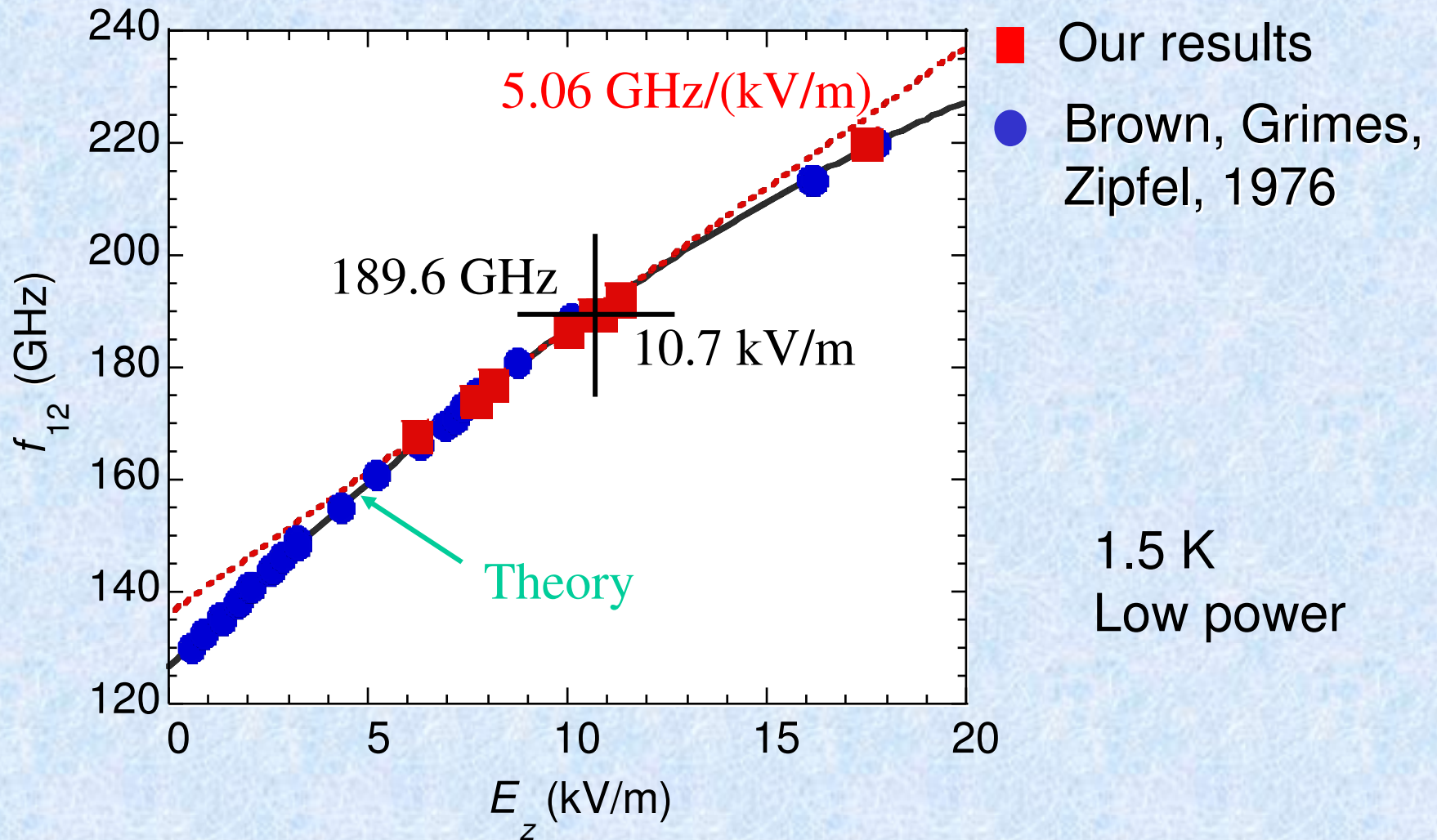
High Microwave Power

- Absorption saturation
- Power broadening
- Absorption hysteresis



Cell

Ground state to first excited Rydberg state
 Resonant frequency f_{12} increases with E_z



Low temperatures

Inhomogenous broadening

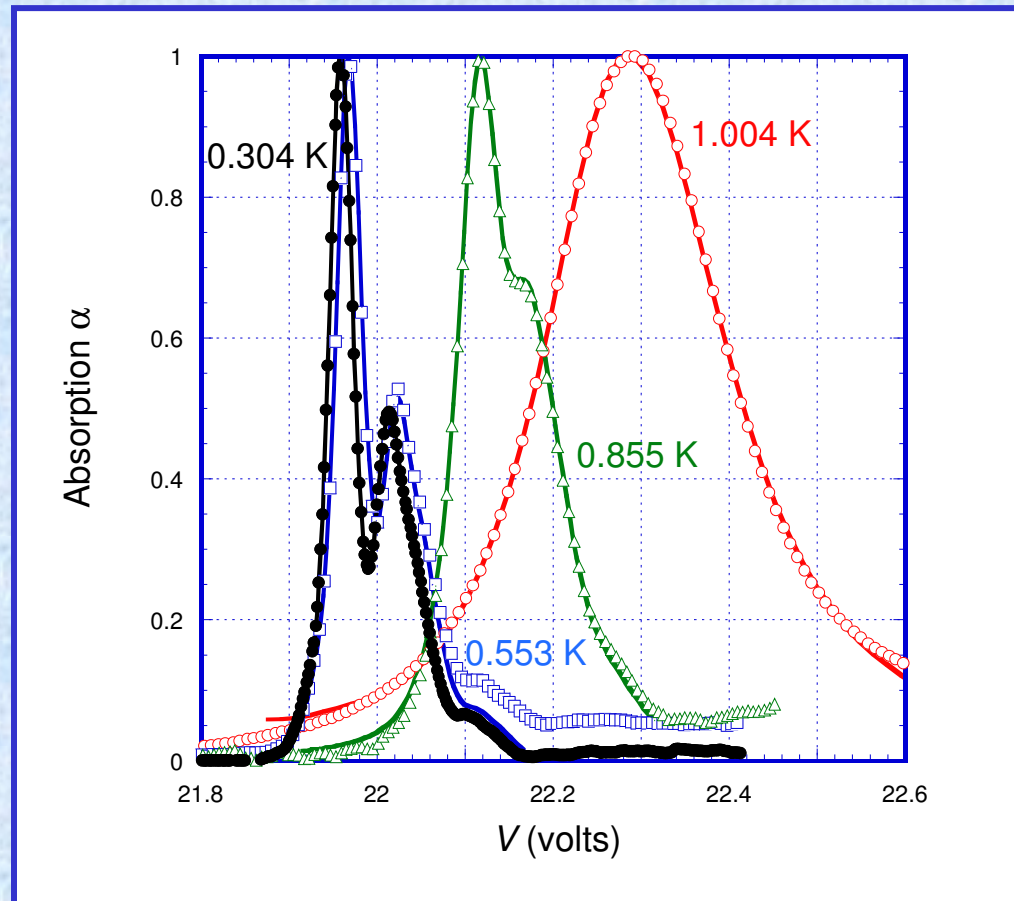
Medium temperatures

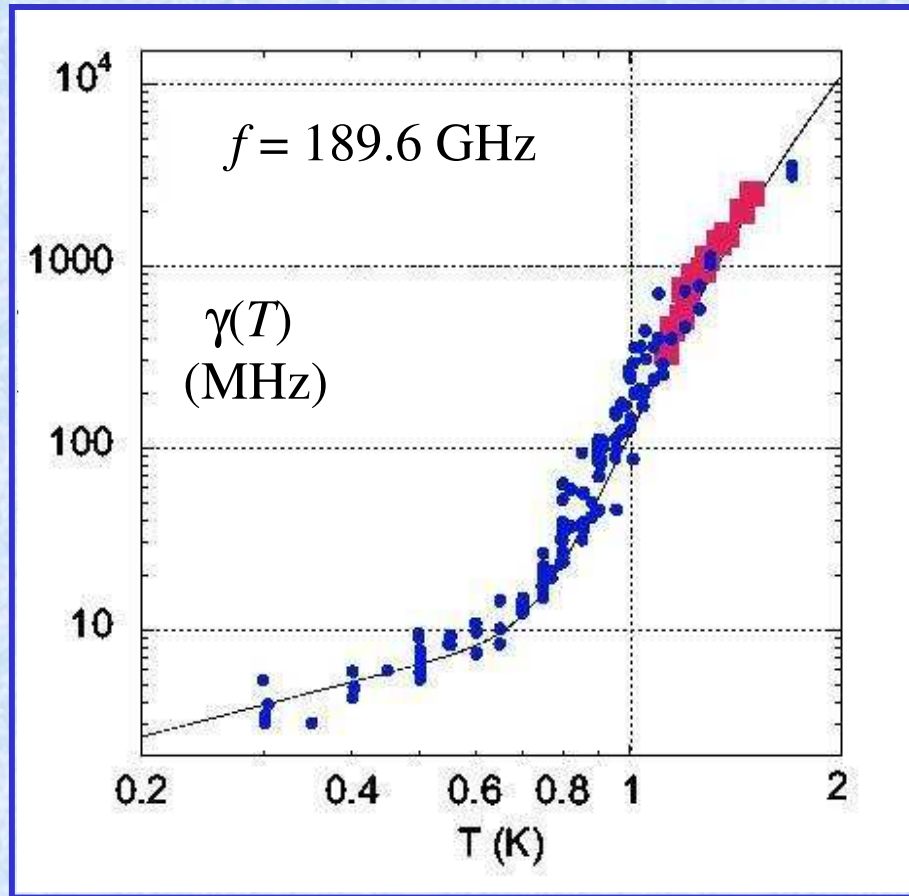
Inhomogenous broadening convoluted with a Lorentzian

High temperatures

Lorentzian broadening

Resonance frequency *decreases* as the temperature *increases*





■ Grimes *et al.* (1976)

Theory: Ando (1976)

$$\gamma = AT + BN_{gas}$$

Ripplon Gas atom
Scattering

NB not the absolute linewidth
Inhomogeneous broadening
plus a contribution $\gamma(T)$

E.Collin *et al.* PRL **89**, 245301 (2002)

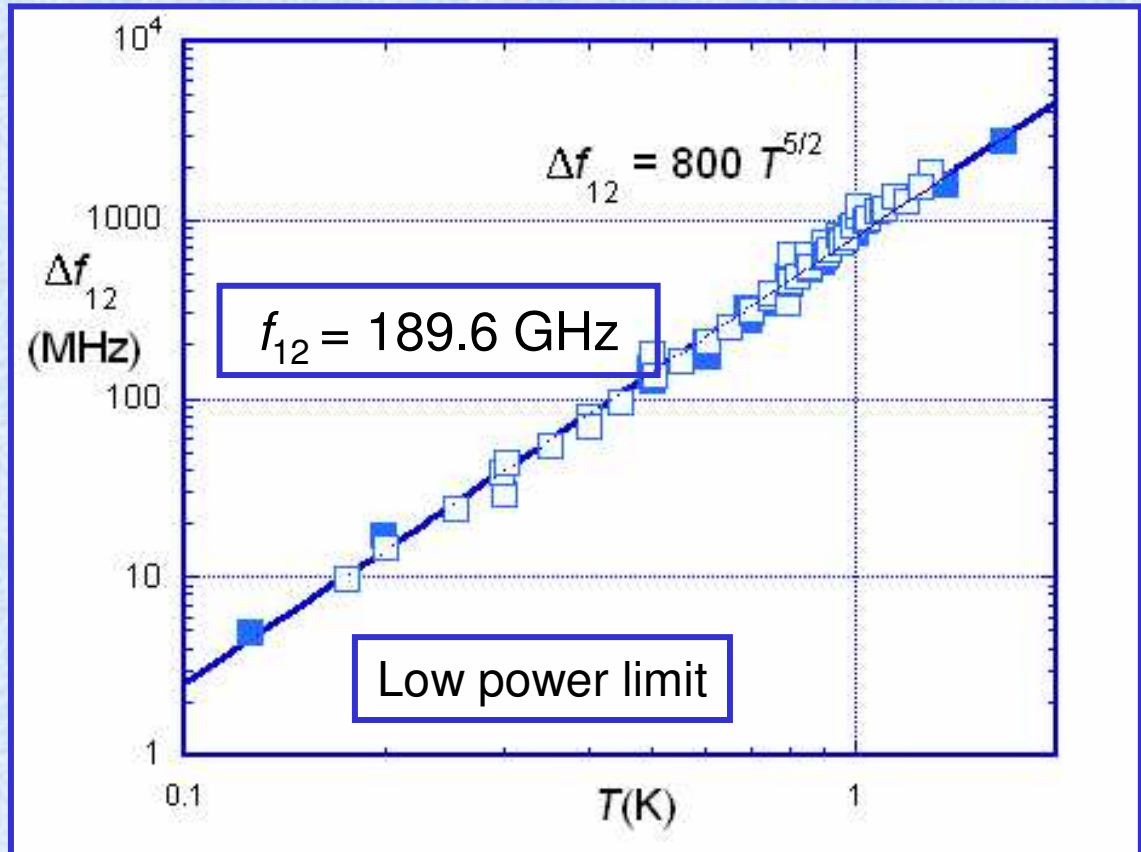
$$\Delta f_{12}(T) = f_{12}(0) - f_{12}(T) \approx 800 \text{ MHz at } 1 \text{ K}$$

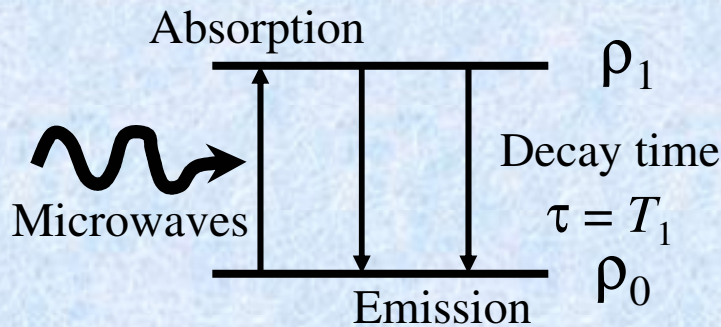
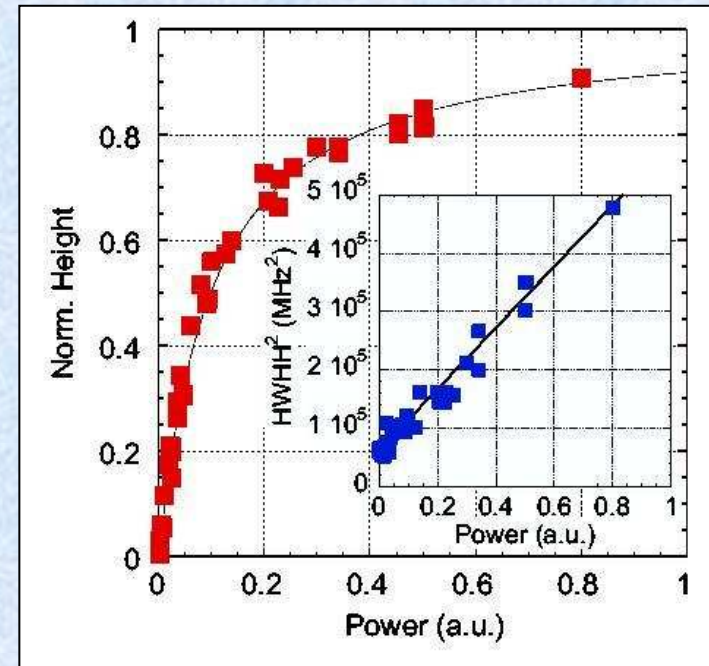
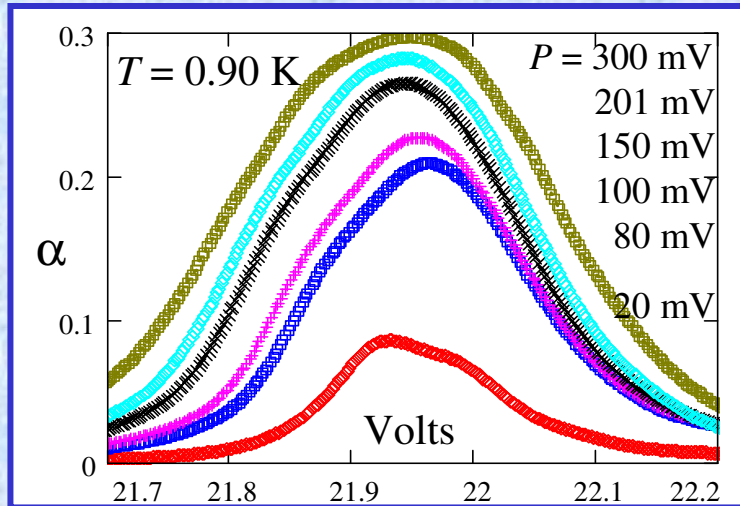
$$\Delta f_{12}(T) \propto T^{5/2} \text{ or } \propto T^{7/3}$$

b

T -dependent surface profile and potential well

2-rippion effects?





2-level system?

Rabi frequency Ω
 $\Omega^2 \propto \text{Power}$

$$\alpha = \frac{0.5N\gamma\Omega^2}{\delta^2 + \gamma^2 + \gamma\tau\Omega^2}$$

$$\gamma_P^2 = \gamma^2 + \gamma\tau\Omega^2$$

BUT:
 Heating?
 Higher sub-bands?
 Bleaching?

Vertical transitions

Microwave absorption/emission

$$1 \leftrightarrow 2$$

Energy relaxation

$$\tau_E: N \rightarrow 2 \rightarrow 1 ; 1 \rightarrow 1$$

(1-ripplon and 2-ripplon)

Horizontal transitions

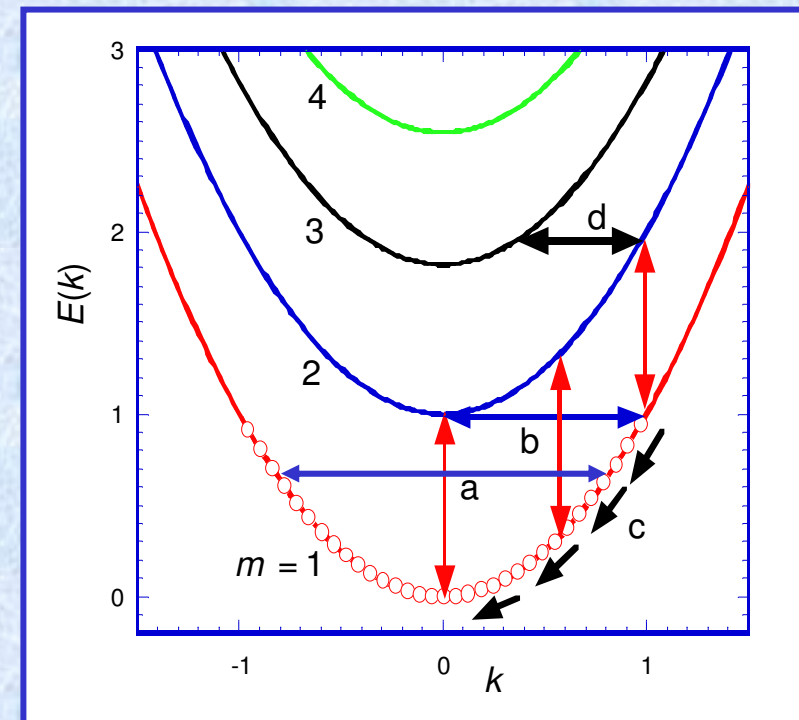
Momentum scattering

$$\tau_k: N \leftrightarrow 2 \leftrightarrow 1 ; 1 \leftrightarrow 1$$

(1-ripplon + gas atom)

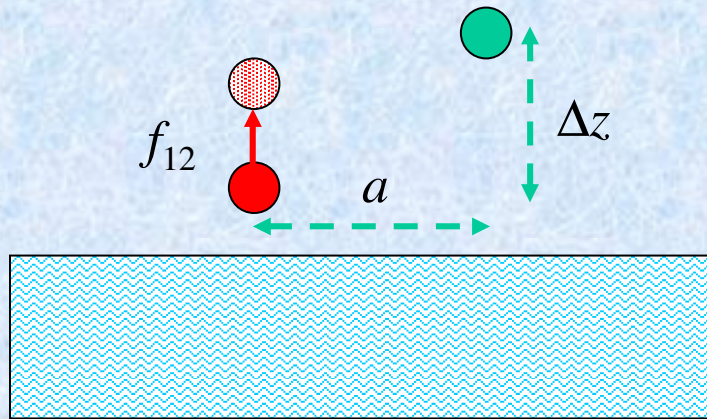
Thermal equilibrium

Electron-electron scattering τ_{ee}



$$\tau_{ee} \ll \tau_k \ll \tau_E$$

Microwave energy \rightarrow Very hot electrons \rightarrow Excited sub-bands
 \rightarrow Bleaching + Population saturation
 \rightarrow Power broadening + Absorption saturation



$$\Delta f_{12} = \frac{e^2 \Delta z^2}{4\pi\epsilon_0 \hbar a^3}$$

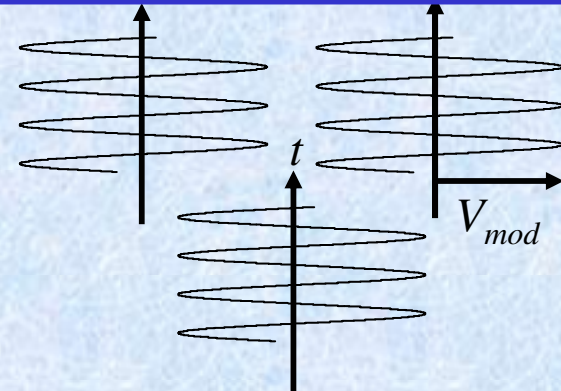
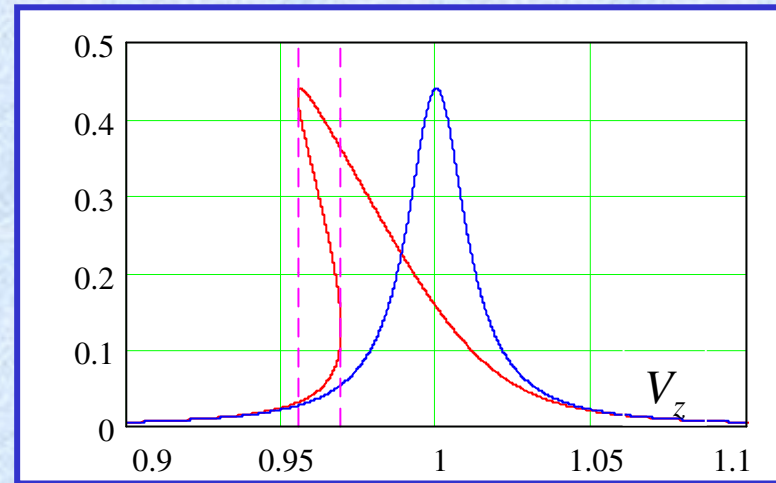
Resonance frequency shifts with

- Electron density
- Power absorbed (excited state population)

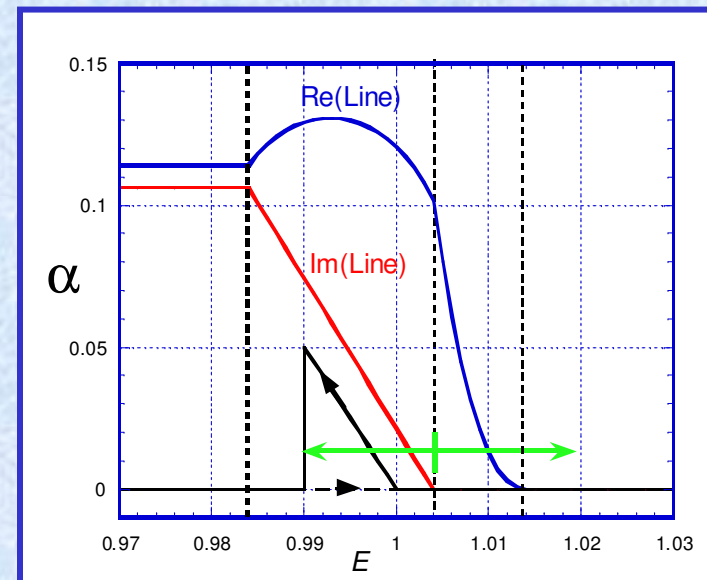
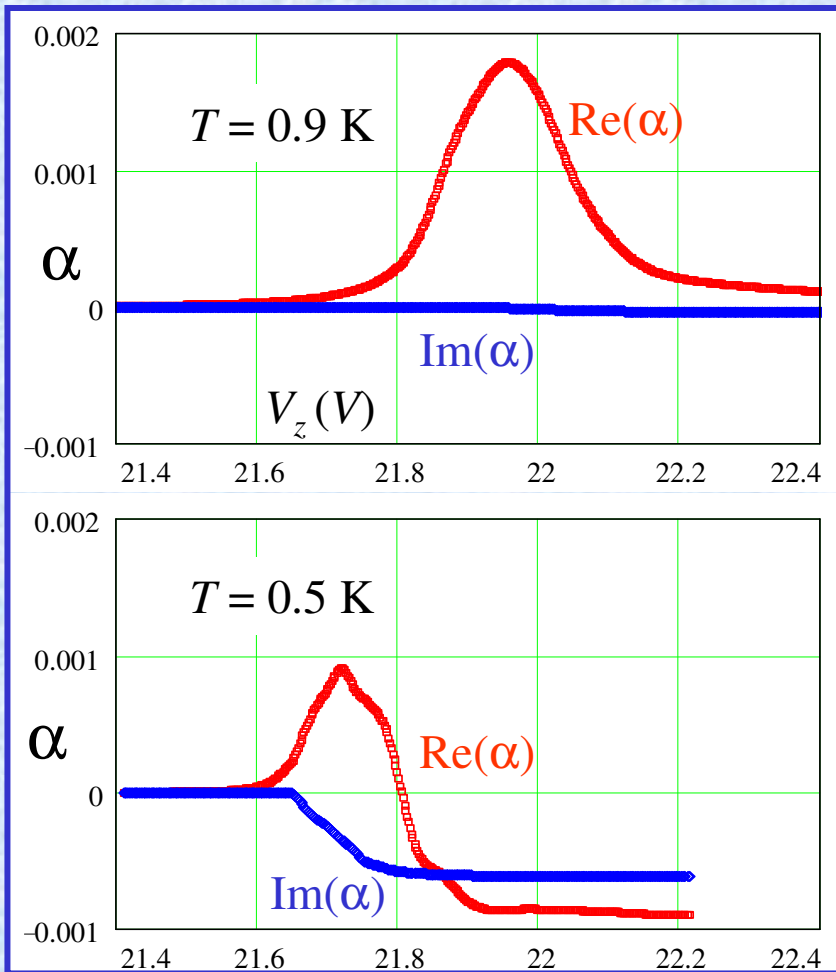
$$\Delta f_{12} \approx 34 \text{ MHz}$$

$$n = 10^{11} \text{ m}^{-2}$$

2-level saturation



Finite a.c. voltage modulation



Low Microwave Power

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